

PerFET™ Power Transistor

FEATURES

- Excellent FOM
- AEC-Q101 Qualified
- Wettable Flank leads for Enhanced AOI
- 100% UIS and Rg tested
- 175°C Operating Junction Temperature
- RoHS Compliant
- Halogen-Free

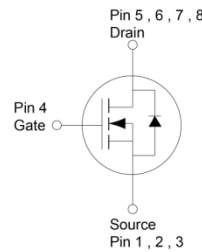
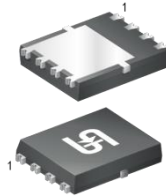
APPLICATIONS

- Automotive Applications
- Solenoid and Motor Drivers
- DC-DC Converters

PRODUCT SUMMARY			
PARAMETER		VALUE	UNIT
V_{DS}		40	V
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	3.2	mΩ
	$V_{GS} = 7V$	3.8	
Q_g	$V_{GS} = 10V$	45	nC



PDFN56U



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	40	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current, Silicon limited	$T_C = 25^\circ\text{C}$	I_D	143	A
Continuous Drain Current (Note 1)	$T_C = 25^\circ\text{C}$	I_D	81	A
	$T_C = 100^\circ\text{C}$		81	
	$T_A = 25^\circ\text{C}$		23	
Pulsed Drain Current (Note 2)		I_{DM}	324	A
Single Pulse Avalanche Current (Note 3)		I_{AS}	32.4	A
Single Pulse Avalanche Energy (Note 3)		E_{AS}	157	mJ
Total Power Dissipation	$T_C = 25^\circ\text{C}$	P_D	115	W
	$T_C = 125^\circ\text{C}$		38	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55 to +175	$^\circ\text{C}$

THERMAL RESISTANCE			
PARAMETER	SYMBOL	MAXIMUM	UNIT
Thermal Resistance – Junction to Case	$R_{\theta JC}$	1.3	$^\circ\text{C/W}$
Thermal Resistance – Junction to Ambient (Note 4)	$R_{\theta JA}$	50	$^\circ\text{C/W}$

NOTE:

1. Package current limit.
2. Pulse Width $\leq 100\mu\text{s}$.
3. $L = 0.3\text{mH}$, $V_{GS} = 10V$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$.
4. Device on a PCB FR4 with 1 in² (single layer, 2 oz thick) copper area for drain connection.

ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 1mA	BV _{DSS}	40	--	--	V
Gate Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA	V _{GS(TH)}	2.4	3	3.6	V
Gate-Source Leakage Current	V _{GS} = ±20V, V _{DS} = 0V	I _{GSS}	--	--	±100	nA
Drain-Source Leakage Current	V _{GS} = 0V, V _{DS} = 40V	I _{DSS}	--	--	1	μA
	V _{GS} = 0V, V _{DS} = 40V T _J = 125°C		--	--	100	
Drain-Source On-State Resistance (Note 5)	V _{GS} = 10V, I _D = 40A	R _{DS(on)}	--	2.7	3.2	mΩ
	V _{GS} = 7V, I _D = 40A		--	3.2	3.8	
Forward Transconductance (Note 5)	V _{DS} = 10V, I _D = 10A	g _{fs}	--	56	--	S
Dynamic (Note 6)						
Total Gate Charge	V _{GS} = 7V, V _{DS} = 20V, I _D = 23A	Q _g	--	32.4	48.6	nC
Total Gate Charge	V _{GS} = 10V, V _{DS} = 20V, I _D = 23A	Q _g	--	45	67.5	
Gate-Source Charge		Q _{gs}	--	14	28	
Gate-Drain Charge		Q _{gd}	--	9.5	19	
Input Capacitance	V _{GS} = 0V, V _{DS} = 25V, f = 1.0MHz	C _{iss}	--	2896	4344	pF
Output Capacitance		C _{oss}	--	562	1124	
Reverse Transfer Capacitance		C _{rss}	--	32	64	
Gate Resistance	f = 1.0MHz	R _g	--	0.7	--	Ω
Switching (Note 7)						
Turn-On Delay Time	V _{GS} = 10V, V _{DS} = 20V, I _D = 23A, R _G = 3.3Ω	t _{d(on)}	--	15.7	--	ns
Rise Time		t _r	--	71	--	
Turn-Off Delay Time		t _{d(off)}	--	28.6	--	
Fall Time		t _f	--	13	--	
Source-Drain Diode						
Diode Forward Voltage (Note 5)	V _{GS} = 0V, I _S = 40A	V _{SD}	--	--	1.1	V
Reverse Recovery Time	I _S = 23A,	t _{rr}	--	42	--	ns
Reverse Recovery Charge	di/dt = 100A/μs	Q _{rr}	--	43	--	nC

Notes:

- Pulse test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
- Defined by design. Not subject to production test.
- Switching time is essentially independent of operating temperature.

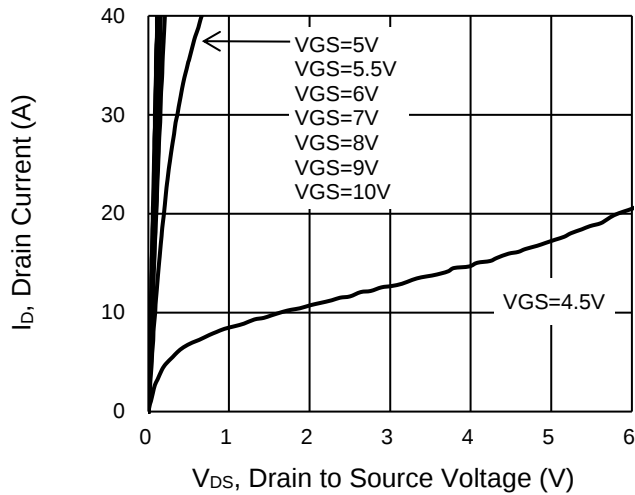
ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TQM032NH04CR RLG	PDFN56U	2,500pcs / 13" Reel

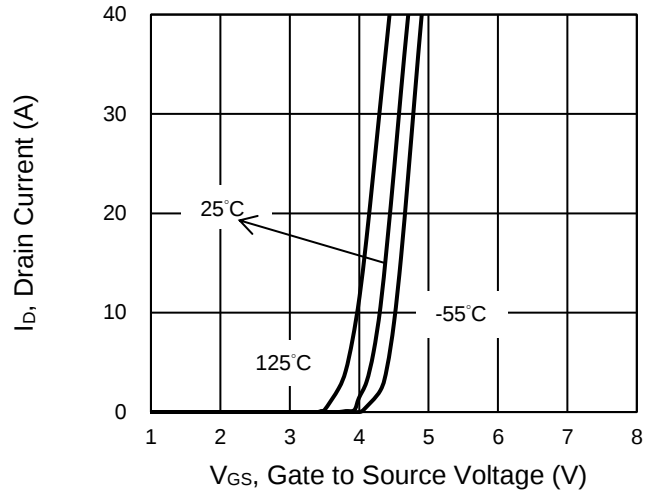
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

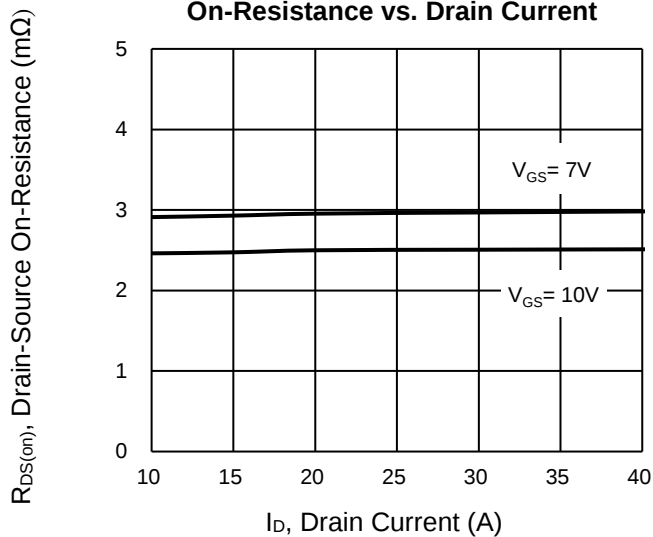
Output Characteristics



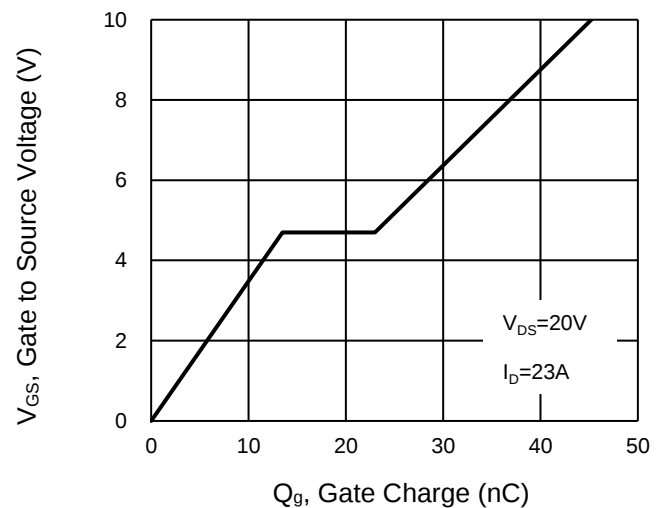
Transfer Characteristics



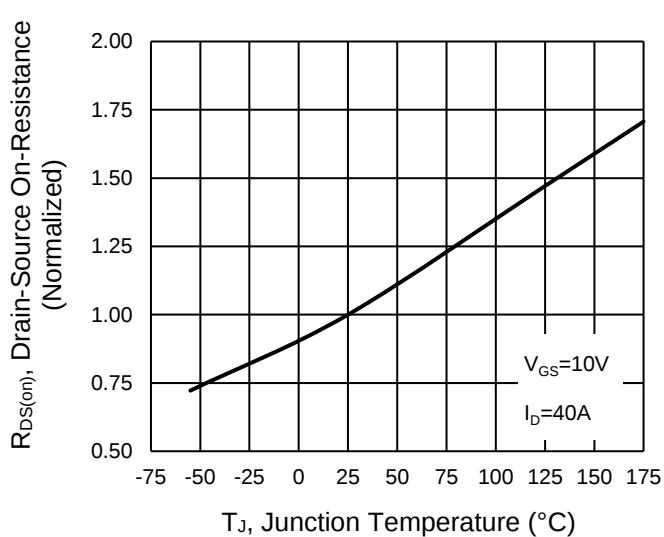
On-Resistance vs. Drain Current



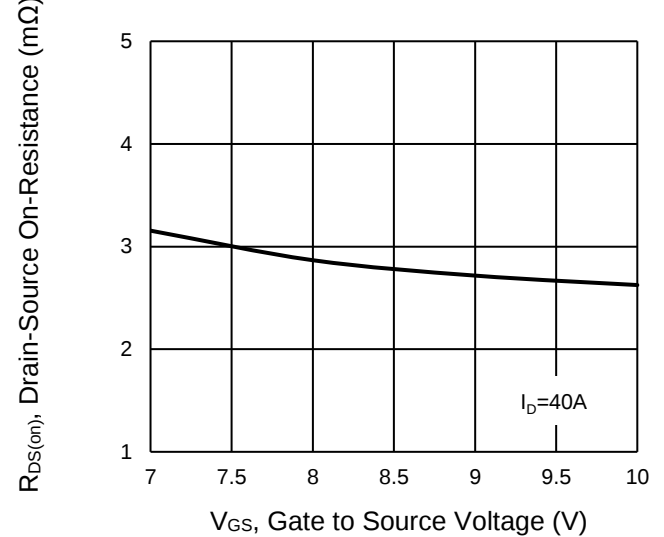
Gate-Source Voltage vs. Gate Charge



On-Resistance vs. Junction Temperature



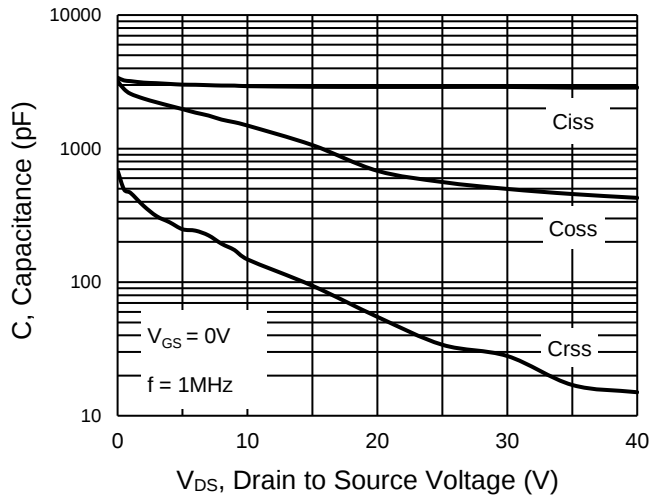
On-Resistance vs. Gate-Source Voltage



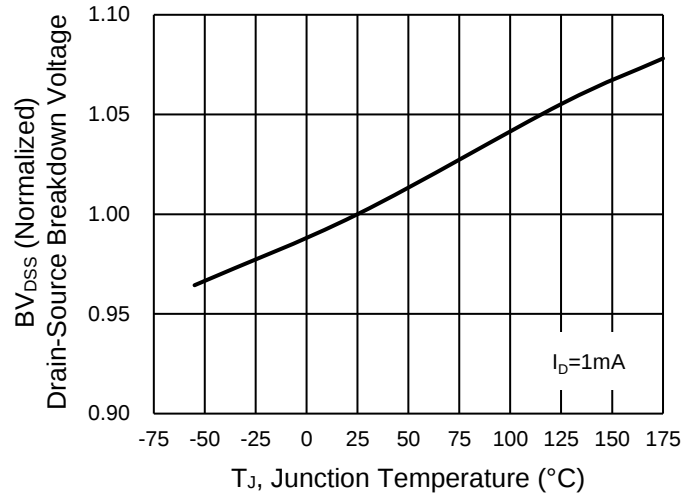
CHARACTERISTICS CURVES

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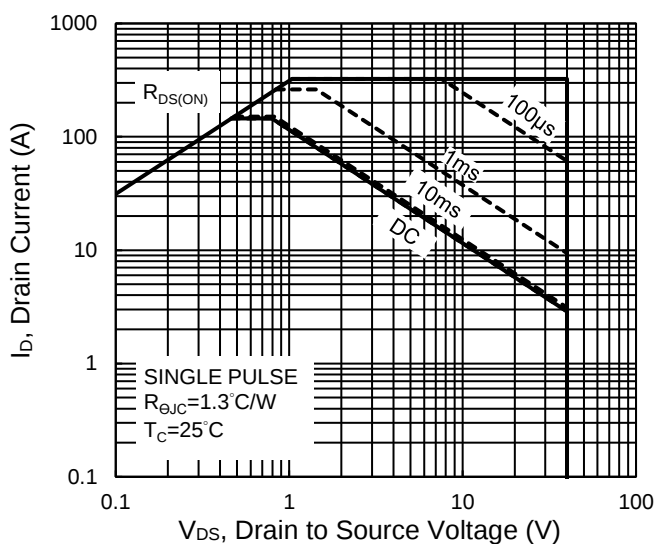
Capacitance vs. Drain-Source Voltage



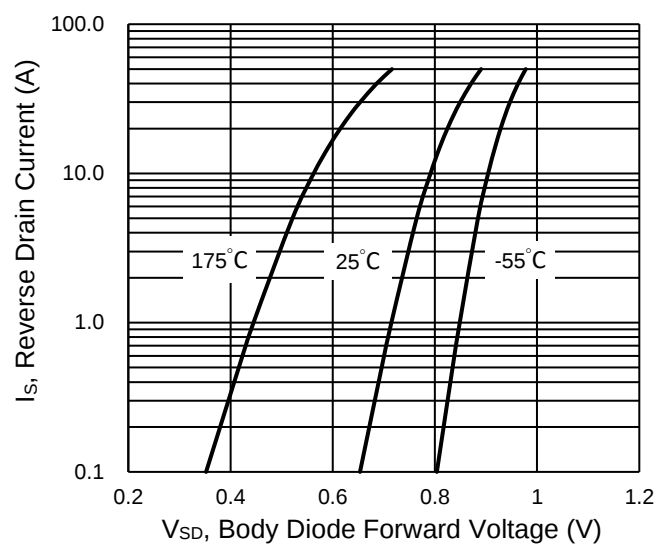
BV_{DSS} vs. Junction Temperature



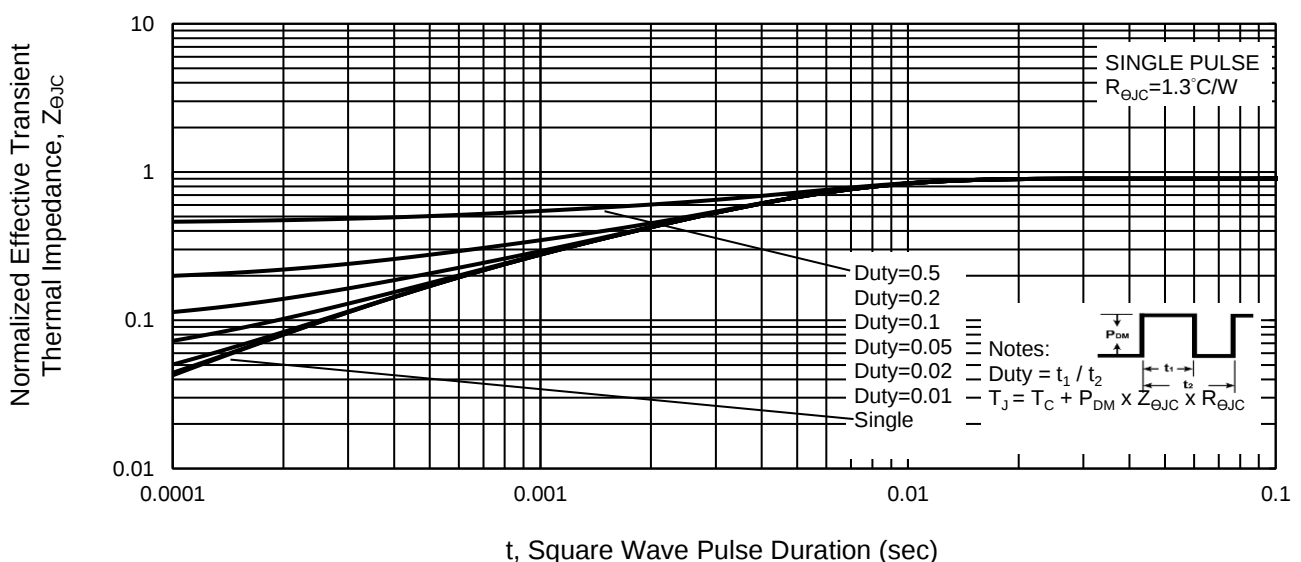
Maximum Safe Operating Area, Junction-to-Case



Source-Drain Diode Forward Current vs. Voltage

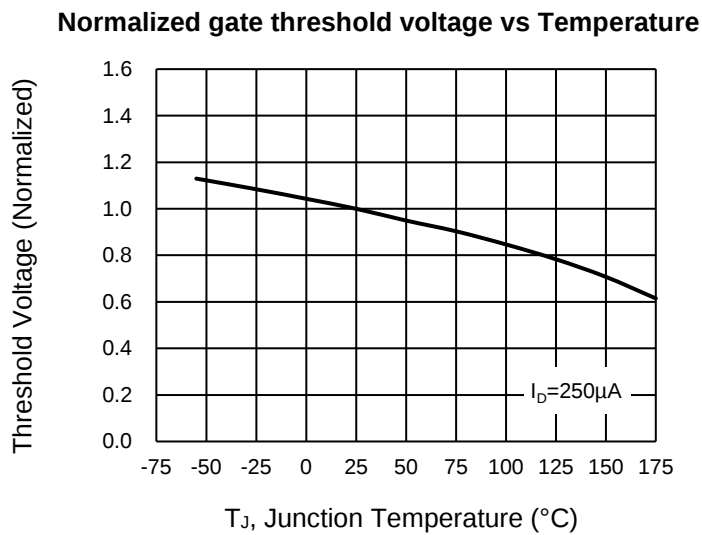
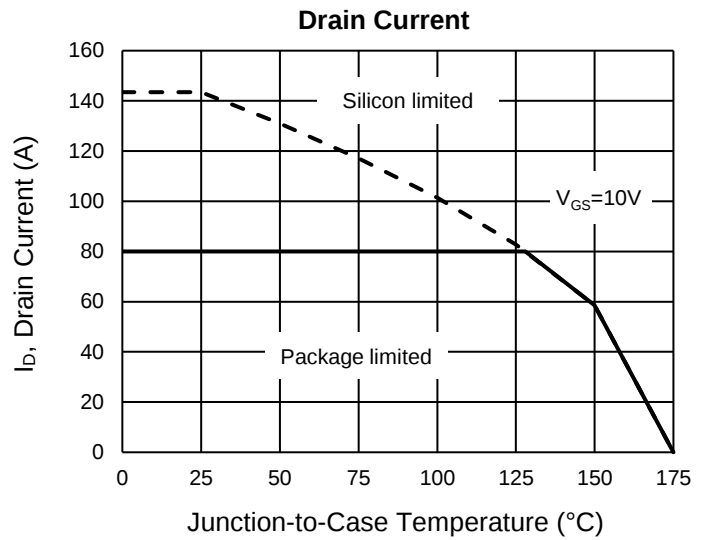
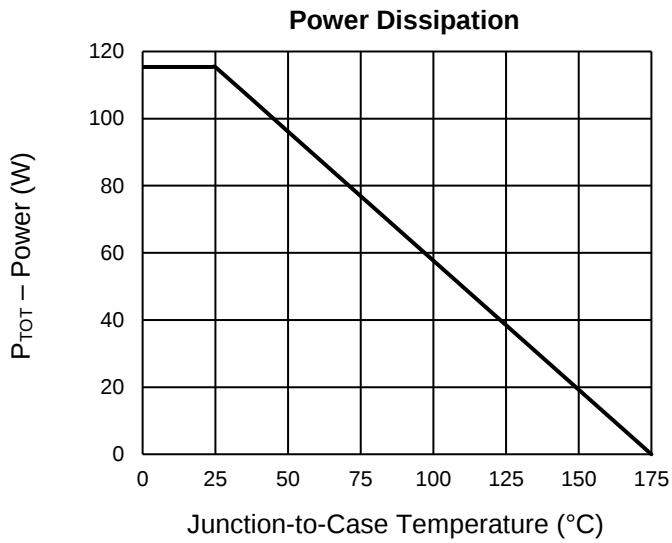


Normalized Thermal Transient Impedance, Junction-to-Case



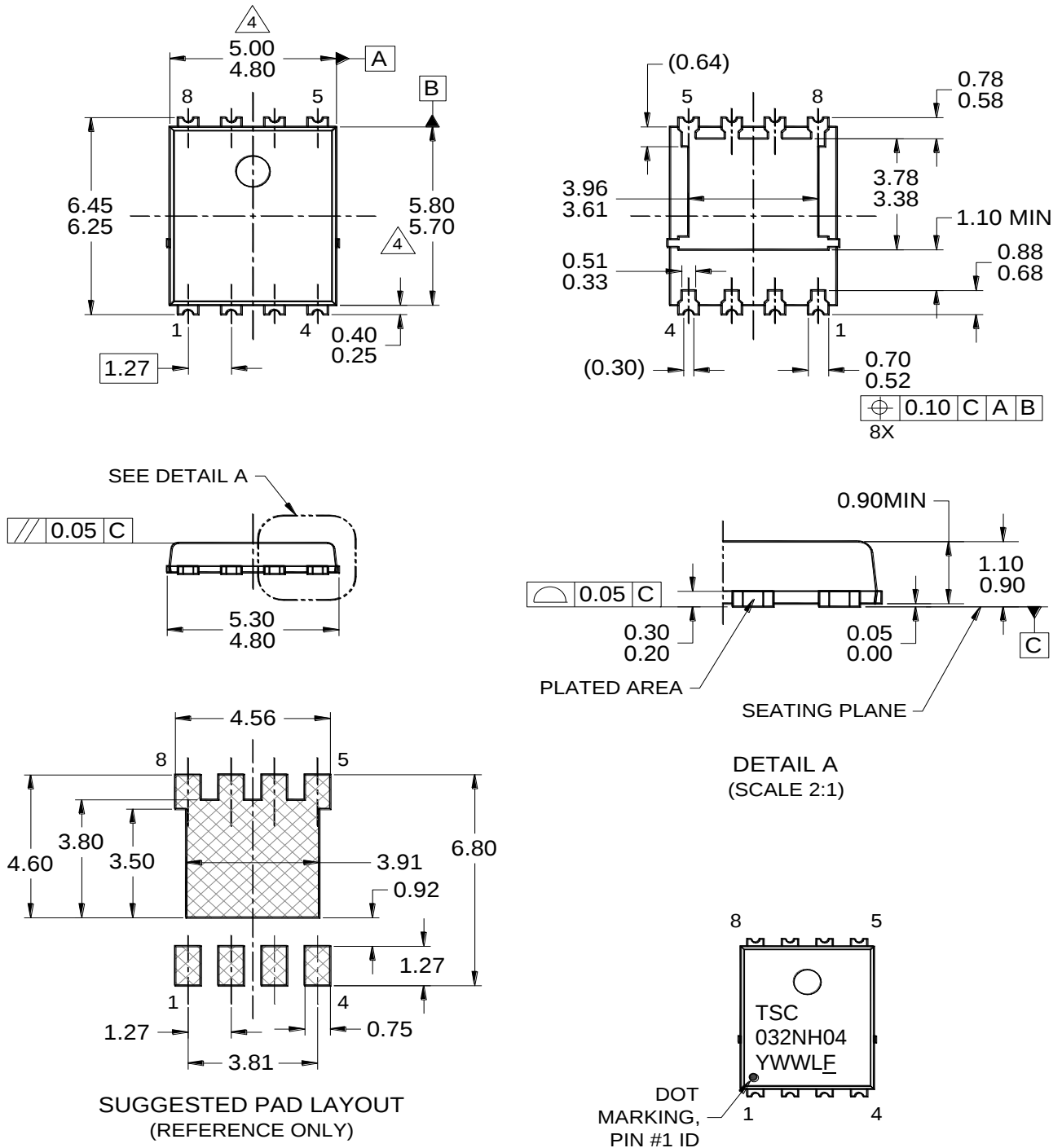
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

PDFN56U



NOTES: UNLESS OTHERWISE SPECIFIED

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. PACKAGE OUTLINE REFERENCE: JEITA ED-7500B, EIAJ SC-111BB.
4. MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
5. DWG NO. REF: HQ2SD07-PDFN56U-023 REV B.

Y = YEAR CODE
WW = WEEK CODE (01-52)
L = LOT CODE (1-9, A-Z)
F = FACTORY CODE
- = AEC-Q101 QUALIFIED

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